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Investigating the Photoyield of Spacecraft Materials

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Investigating the Photoyield of Spacecraft Materials Jennifer Albretsen, Ryan Hoffman, J.R. Dennison Utah State University Physics Department

BACKGROUND: PHOTO-INDUCED SPACECRAFT CHARGING

The photoelectric effect is an important contributor to spacecraft charging.

• When photons of energies greater than the work function or electron affinity (threshold energy) of a material interact with embedded electrons, the photoelectric effect, or photoelectron emission occurs.

Photoelectron emission leaves a surface positively charged. One of several factors contributing to spacecraft charging.

Important to understand photoelectron emissions for energy ranges of high solar photon flux. (See Fig.1)



• Photoemissions can contribute to charging of conductors, semicondcutors, and insulators used in the James Webb Space Telescope and Solar Probe Mission studies. (See figures 2 and 3)

Photo-induced currents more difficult to measure in semiconductors and insulators. 1. Photon energy must be greater than band gap for photoelectric effect to occur. 2. Low conductivity \rightarrow Induced charging more difficult to detect.



Fig. 2: NASA/JPL Solar Probe model.



INSTRUMENTATION FOR PHOTOYIELD MEASUREMENTS

Instrumentation was upgraded to better detect the photoemissions of semiconducting and insulating materials.

Upgraded photoyield measurement system (see Fig. 4)

- PC controls monochromator.
- Light from monochromator is pulsed at constant frequency using light chopper.
- Pulsed light passes through MgF window and contacts sample in vacuum.
- Sample current converted to voltage signal by picoammeter.
- The Lock-in amplifer references chopper frequency and amplifies sample signal of the same frequency. Resulting spectra data are read into computer.

Fig. 5: Dodecahedral sample carousel containing: a) 1cm diameter sample billet and b)photodiode.

Photoemission spectra were measured for conducting, semiconducting, and insulating materials used in NASA's James Webb Space Telescope and Solar Probe Mission studies to determine the contribution of photoemissions to overall spacecraft charging.

• A vapor-deposited conductor used in James Webb Space Telescope study. Top layer: 100 nm layer of Vapor Deposited Aluminum (VDA).

Mid layer: 1 mil layer of Kapton E (PI-E), a DuPontTM polymeric insulator.

Bottom layer: 60 nm layer of silicon alloyed with Iron (Fe), Chromium (Cr), Nickel (Ni).

No photo-induced current detected. (See Fig. 13)

High reflectivity in monochromator range (2eV to 6.75 eV). (See Fig. 14)

e Spectrum	Sample Reflectance	_
	Gellectinee (%) Rellectinee (%)	-
8 9	Photon energy (eV)	

Fig. 13: Photoemission Spectra for VDA x PI-E x Si Fig. 14: Graph of Percent Reflectivity vs. Energy for VDA.

Photoemission spectra correlate with conductivity and reflectivity of materials.

Measured work function value (4.65 eV) agrees with accepted value for gold (~4.8eV). • Used as standard to verify that upgraded instrumentation is accurate.

• Work function of aluminum (~4 eV) is within the monochromator's range, but no photo-induced

• Absence of photoyield likely due to high reflectivity of Vapor Deposited Aluminum (see Fig. 14)

• Observed photo-induced current beginning at 5.25 eV correlates with band gap of Si alloy. • Photoemission current intensity much lower than gold (relative to the noise level). This is expected, since gold (a metal) is more conductive than the Si alloy (a semiconductor.)

• No photo-induced current was observed, likely because the band gap of PBN exceeds the monochromator transmission threshold. Higher energy light source needed to determine photoyield threshold energy.

• No photo-induced current was observed, likely because the band gap of PBN exceeds the monochromator transmission threshold.

Higher energy light source needed to determine photoyield threshold energy.

1. Take photoyield measurements for semi-transparent insulators, such as Kapton. 2. Refine lock-in amplifier technique to improve detection of subtle photo-induced currents. 3. Use higher energy monochromated light source to determine threshold photoemission energies of

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